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STMicroelectronics ESDARF03-1BF3

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ESDARF03-1BF3

Ultralow capacitance ESD protection for antenna

Features

- ultralow diode capacitance 0.6 pF
- Single line, protected against 15 kV ESD
- breakdown voltage V_{BR} = 6.0 V min.
- Flip Chip 400 µm pitch, lead-free
- very low leakage current
- very small PCB area
- RoHS compliant

Benefits

- minimized impact on rise and fall times for maximum data integrity
- low PCB space occupation
- higher reliability through monolithic integration

Complies with the following standards

- IEC 61000-4-2 level 4:
 - 15 kV (air discharge)
 - 8 kV (contact discharge)
- MIL STD 883G Method 3015.7:
 - 25 kV (human body model)

Applications

- antenna protection
- DVB H
- GPS

Description

The ESDARF03-1BF3 is a monolithic, application specific discrete device dedicated to ESD protection of antennas.

Its ultralow line capacitance secures a high level of signal integrity without compromising the protection of sensitive chips against the most stringently characterized ESD strikes.

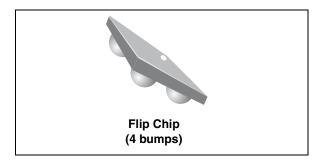


Figure 1. Pin layout (bump side)

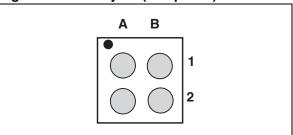
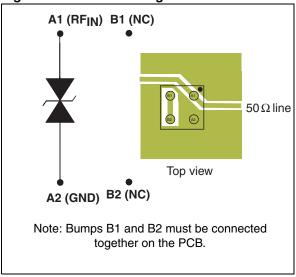


Figure 2. Device configuration



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November 2010 Doc ID 16078 Rev 1 1/7



Characteristics ESDARF03-1BF3

1 Characteristics

Table 1. Absolute maximum ratings $(T_{amb} = 25 \, ^{\circ}C)$

Symbol	Parameter	Value	Unit
V _{PP}	ESD discharge IEC 61000-4-2, air discharge ESD discharge IEC 61000-4-2, contact discharge	15 8	kV
P _{PP}	Peak pulse power dissipation (8/20 μs)	60	W
T _j	Maximum junction temperature	125	°C
T _{op}	Operating temperature range	-30 to + 85	°C
T _{stg}	Storage temperature range	-55 to +150	°C

Figure 3. Electrical characteristics (definitions)

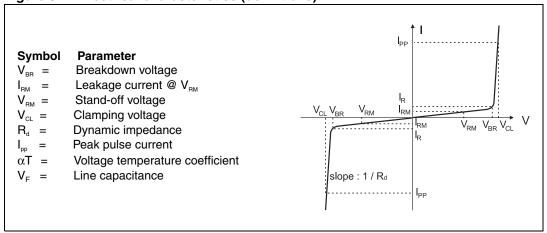
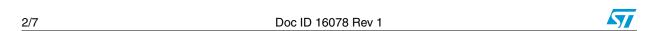


Table 2. Electrical characteristics ($T_{amb} = 25 \, ^{\circ}C$)

Symbol	Test conditions	Min.	Тур.	Max.	Unit
V_{BR}	I _R = 1 mA	6	9		V
I _{RM}	$V_{RM} = 3 V$			100	nA
R _d	Exponential wave form 8/20 μ s, $I_{pp} = 1$ to 5 A		2.6		Ω
αΤ	I _R = 1 mA			5	10 ⁻⁴ / °C
C _{line}	V _{LINE} = 0 V, V _{OSC} = 30 mV, F = 1 MHz		0.6	0.8	pF





ESDARF03-1BF3 Characteristics

Figure 4. ESD response to IEC 61000-4-2 (+8 kV contact discharge)

Figure 5. ESD response to IEC 61000-4-2 (-8 kV contact discharge)

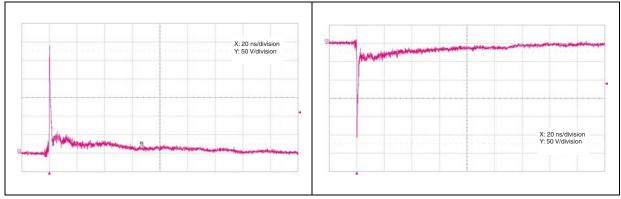


Figure 6. Junction capacitance versus frequency (typical values)

Figure 7. S21 attenuation measurement

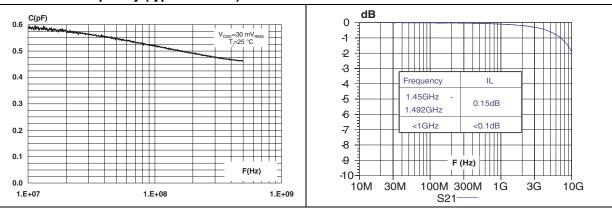
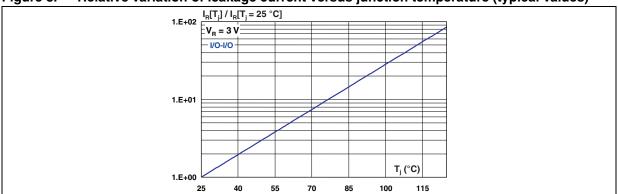


Figure 8. Relative variation of leakage current versus junction temperature (typical values)



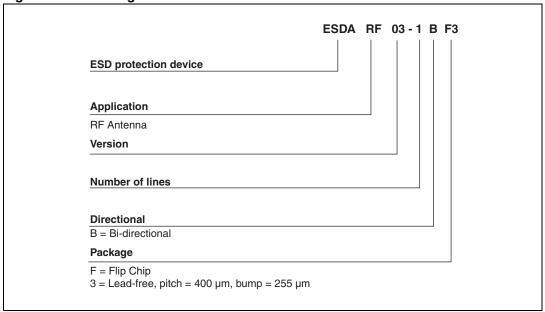


Ordering information scheme

ESDARF03-1BF3

2 Ordering information scheme

Figure 9. Ordering information scheme







ESDARF03-1BF3 Package information

3 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 10. Package dimensions

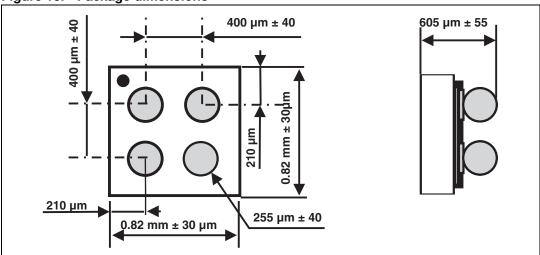
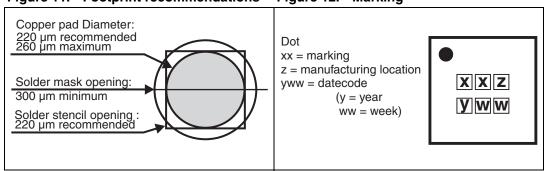


Figure 11. Footprint recommendations Figure 12. Marking

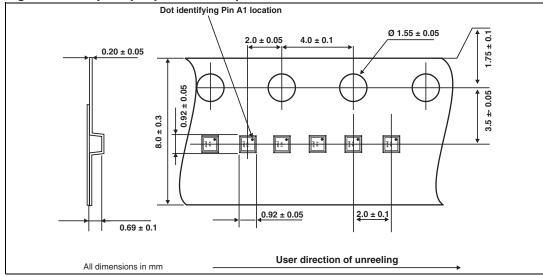




Ordering information

ESDARF03-1BF3





Note: More information is available in the application notes:

AN2348: "400 μm Flip Chip: Package description and recommendations for use"

AN1751: "EMI Filters: Recommendations and measurements"

4 Ordering information

Table 3. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
ESDARF03-1BF3	R3	Flip Chip	0.91 mg	5000	Tape and reel (7")

5 Revision history

Table 4. Document revision history

Date	Revision	Changes
15-Nov-2010	1	Initial release.

6/7 Doc ID 16078 Rev 1



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Datasheet of ESDARF03-1BF3 - TVS DIODE 3VWM FLIPCHIP

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ESDARF03-1BF3

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